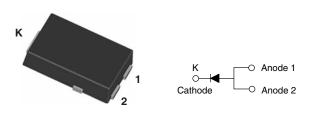
### **Vishay Semiconductors**

# Hyperfast Rectifier, 6 A FRED Pt®



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TO-277A (SMPC)

| PRODUCT SUMMARY                  |                |  |  |  |  |  |
|----------------------------------|----------------|--|--|--|--|--|
| Package                          | TO-277A (SMPC) |  |  |  |  |  |
| I <sub>F(AV)</sub>               | 6 A            |  |  |  |  |  |
| V <sub>R</sub>                   | 600 V          |  |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.05 V         |  |  |  |  |  |
| t <sub>rr (typ.)</sub>           | 33 ns          |  |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C         |  |  |  |  |  |
| Diode variation                  | Single die     |  |  |  |  |  |

### FEATURES

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC, CRM/CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <a href="http://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                          |             |       |  |  |  |  |
|---|-----------------------------------|--------------------------|-------------|-------|--|--|--|--|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS          | VALUES      | UNITS |  |  |  |  |
| Peak repetitive reverse voltage             | V <sub>RRM</sub>                  |                          | 600         | V     |  |  |  |  |
| Average rectified forward current           | I <sub>F(AV)</sub>                | T <sub>Sp</sub> = 145 °C | 6           |       |  |  |  |  |
| Non-repetitive peak surge current           | I <sub>FSM</sub>                  | T <sub>J</sub> = 25 °C   | 90          | A     |  |  |  |  |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                          | -65 to +175 | °C    |  |  |  |  |

| <b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \ ^{\circ}C$ unless otherwise specified) |                                     |  |     |      |      |       |  |
|---|-------------------------------------|--|-----|------|------|-------|--|
| PARAMETER   | SYMBOL                              | SYMBOL TEST CONDITIONS                           |     | TYP. | MAX. | UNITS |  |
| Breakdown voltage,<br>blocking voltage  | V <sub>BR</sub> ,<br>V <sub>R</sub> | I <sub>R</sub> = 100 μA                          | 600 | -    | -    |       |  |
| Forward voltage   | V <sub>F</sub>                      | I <sub>F</sub> = 6 A                             | -   | 1.30 | 1.80 | V     |  |
| Forward voltage   |                                     | I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C    | -   | 1.05 | 1.55 |       |  |
|   | I <sub>R</sub>                      | $V_{R} = V_{R}$ rated                            | -   | -    | 5    |       |  |
| Reverse leakage current   |                                     | $T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$ | -   | 50   | 300  | μΑ    |  |
| Junction capacitance  | CT                                  | V <sub>R</sub> = 600 V                           | -   | 8    | -    | pF    |  |

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COMPLIANT

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| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified) |                  |   |  |      |      |      |         |  |  |
|---|------------------|---|--|------|------|------|---------|--|--|
| PARAMETER   | SYMBOL           | TEST CO   | NDITIONS   | MIN. | TYP. | MAX. | UNITS   |  |  |
|   |                  | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$                | 0 A/µs, V <sub>R</sub> = 30 V  | -    | 33   | -    |         |  |  |
| Povereo recover timo  | t <sub>rr</sub>  | $I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$ |  | -    | -    | 40   |         |  |  |
| Reverse recovery time   |                  | T <sub>J</sub> = 25 °C  |  | -    | 40   | -    | ns      |  |  |
|   |                  | T <sub>J</sub> = 125 °C   | I <sub>F</sub> = 6 A<br>dI <sub>F</sub> /dt = 500 A/μs<br>V <sub>R</sub> = 400 V | -    | 75   | -    |         |  |  |
| Dook roopyony ourrent   | I <sub>RRM</sub> | T <sub>J</sub> = 25 °C  |  | -    | 6.8  | -    | A<br>nC |  |  |
| Peak recovery current   |                  | T <sub>J</sub> = 125 °C   |  | -    | 11   | -    |         |  |  |
| Reverse recovery charge   | Q <sub>rr</sub>  | T <sub>J</sub> = 25 °C  |  | -    | 140  | -    |         |  |  |
|   |                  | T <sub>J</sub> = 125 °C   |  | -    | 400  | -    |         |  |  |

| THERMAL - MECHANICAL SPECIFICATIONS            |                                   |                           |      |        |      |       |  |
|--|-----------------------------------|---------------------------|------|--------|------|-------|--|
| PARAMETER                                      | SYMBOL                            | TEST CONDITIONS           | MIN. | TYP.   | MAX. | UNITS |  |
| Maximum junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub> |                           | -65  | -      | 175  | °C    |  |
| Thermal resistance,<br>junction to solder pad  | R <sub>thJ-Sp</sub>               |                           | -    | 2.4    | 3.5  | °C/W  |  |
| Approximate weight                             |                                   |                           |      | 0.1    |      | g     |  |
| Approximate weight                             |                                   |                           |      | 0.0035 |      | oz.   |  |
| Marking device                                 |                                   | Case style TO-277A (SMPC) |      | NE     | H6   |       |  |

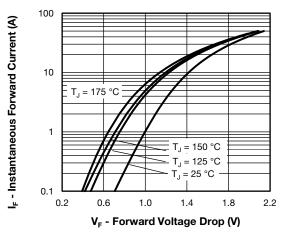


Fig. 1 - Typical Forward Voltage Drop Characteristics

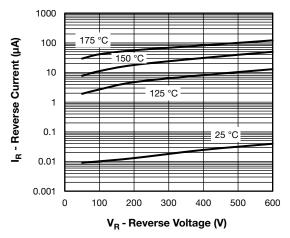


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

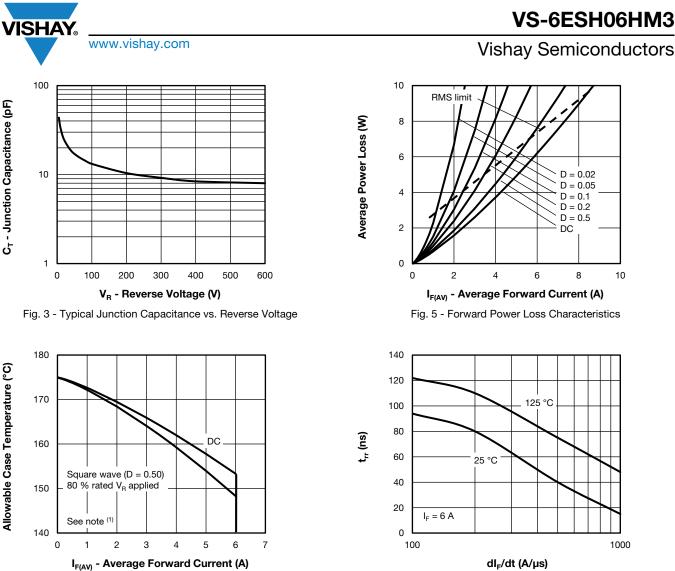


Fig. 4 - Maximum Allowable Case Temperature

vs. Average Forward Current



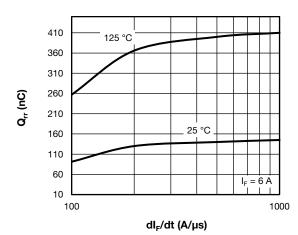


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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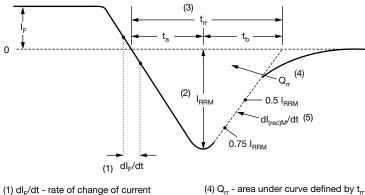
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# VS-6ESH06HM3

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- through zero crossing
- (2)  $I_{\text{RRM}}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$  extrapolated to zero current.

(4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$ and I<sub>RRM</sub>

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 8 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

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**Device cod** 

|   | VS- |   | 6    | Е                                   | S         | н         | 06      | н       | М3       |                |
|---|-----|---|------|-------------------------------------|-----------|-----------|---------|---------|----------|----------------|
| • | 1   |   | 2    | 3                                   | 4         | 5         | 6       | (7)     | 8        |                |
| [ | 1   | - | Vish | nay Serr                            | niconduc  | ctors pro | oduct   |         |          |                |
| [ | 2   | - | Curi | ent ratii                           | ng (6 = 6 | 6 A)      |         |         |          |                |
| [ | 3   | - | Circ | uit confi                           | guratior  | า:        |         |         |          |                |
|   |     |   | E =  | single d                            | liode     |           |         |         |          |                |
| [ | 4   | - | S =  | S = SMPC package                    |           |           |         |         |          |                |
| ĺ | 5   | - | Prod | Process type,                       |           |           |         |         |          |                |
| • |     |   | H =  | H = hyperfast recovery              |           |           |         |         |          |                |
| [ | 6   | - | Volt | Voltage code $(06 = 600 \text{ V})$ |           |           |         |         |          |                |
| [ | 7   | - | H =  | H = AEC-Q101 qualified              |           |           |         |         |          |                |
| Ī | 8   | - | M3 : | = haloge                            | en-free,  | RoHS-0    | complia | nt, and | terminat | tions lead (Pb |

| ORDERING INFORMATION (Example) |                   |                        |                                    |  |  |  |  |
|--------------------------------|-------------------|------------------------|------------------------------------|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION              |  |  |  |  |
| VS-6ESH06HM3/86A               | 1500              | 1500                   | 7" diameter plastic tape and reel  |  |  |  |  |
| VS-6ESH06HM3/87A               | 6500              | 6500                   | 13" diameter plastic tape and reel |  |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95570 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95565 |  |  |  |  |
| Packaging information      | www.vishay.com/doc?88869 |  |  |  |  |

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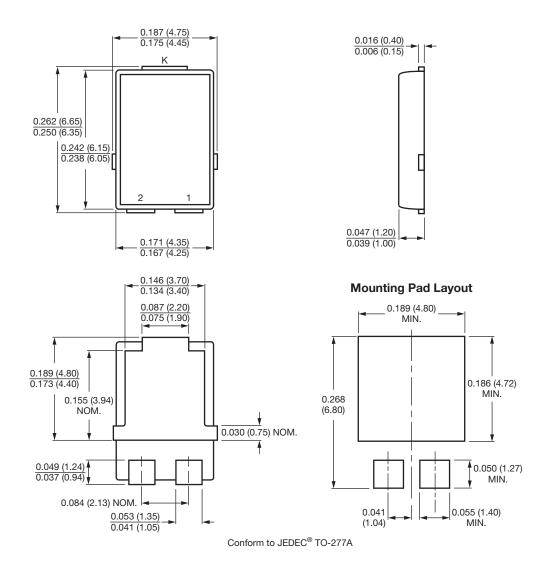
## **Outline Dimensions**





TO-277A (SMPC)

### **DIMENSIONS** in inches (millimeters)





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